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GOODRAM Industrial mSATA SSD

S11 MLC silver-gold-diamond

DATASHEET



Version: 1.2
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mSATA Solid State Drive with SATA interface for Industrial Applications

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REVISION HISTORY

| VERSION | CHANGES | DATE |
|---------|------------------------------|------------|
| 1.0 | Initial release | 03.10.2019 |
| 1.1 | Logo amendment | 16.06.2020 |
| 1.2 | P/N Toshiba/Kioxia amendment | 14.08.2020 |

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PRODUCT OVERVIEW

- **Capacity**
 - 4GB up to 512GB
- **SATA Interface**
 - SATA Revision 3.2
 - SATA 1.5Gbps, 3Gbps and 6Gbps interface
- **Flash Memory**
 - Flash Type: Kioxia 15 nm MLC
 - 1pcs to 4pcs of TSOP/BGA flash
- **Performance**^{Note1}
 - Read: up to 560 MB/s
 - Write: up to 490 MB/s
- **Power Consumption**^{Note2}
 - Active mode: < 2690mW
 - Idle mode: < 285mW
 - DEVSLP mode: < 5mW
- **TBW (terabytes written)**^{Note3}
 - 540 TBW for 512GB
- **RoHS compliant**
- **MTBF**
 - More than 2,000,000 hours
- **Controller**
 - PS3111-S11
- **Advanced Flash Management**
 - Static and Dynamic Wear Leveling
 - Bad Block Management
 - TRIM
 - SMART
 - NQC
 - Over-provisioning
 - Firmware update
 - SmartZIP™
- **Low Power Management**
 - DIPM/HIPM Mode
 - DEVSLP Mode (optional)
- **Temperature Range**^{Note4}
 - Operation (silver): 0 ~+ 70°C
 - Operation (gold): -25°C ~ +85°C
 - Operation (diamond): -40°C ~ +85°C
 - Storage: -40°C ~ +85°C

Notes:

1. Measured by CrystalDiskMark v3.0
2. Please see “Power Consumption” for details.
3. Please see “TBW (Terabyte Written)” for details.
4. According to standards IEC-60068-2-1/2/14/38

PRODUCT DETAILS

GENERAL DESCRIPTION

GOODRAM Industrial mSATA SSD delivers all the advantages of Flash Drive technology with Serial ATA I/II/III interface and is fully compliant with the standard mSATA form factor. The mSATA SSD is designed to operate at a maximum operating frequency of 200MHz with 30MHz external crystal. The capacity could provide a wide range up to 512GB and the performance reach up to 550MB/s read as well as 500MB/s write based on Toggle 2.0 MLC (with 32MB SDR cache enabled and measured by CrystalDiskMark). Meanwhile, the power consumption is much lower than traditional Hard Drives.

FLASH MANAGEMENT

GOODRAM Industrial mSATA MLC SSD utilizes all the state of art technologies to ensure full reliability until the TBW parameter is reached. These technologies include:

Error Correction Code (ECC)

Flash memory cells will deteriorate with use, which might generate random bit errors in the stored data. Thus, SSD drive applies the LDPC (Low Density parity Check) of ECC algorithm, which can detect and correct errors occur during read process, ensure data been read correctly, as well as protect data from corruption.

Wear Leveling

NAND Flash devices can only undergo a limited number of program/erase cycles, and in most cases, the flash media are not used evenly. If some area get updated more frequently than others, the lifetime of the device would be reduced significantly. Thus, Wear Leveling technique is applied to extend the lifespan of NAND Flash by evenly distributing write and erase cycles across the media. Product has advanced Wear Leveling algorithm, which can efficiently spread out the flash usage through the whole flash media area. Moreover, by implementing both dynamic and static Wear Leveling algorithms, the life expectancy of the NAND Flash is greatly improved.

Bad Block Management

Bad blocks are blocks that include one or more invalid bits, and their reliability is not guaranteed. Blocks that are identified and marked as bad by the manufacturer are referred to as "Initial Bad Blocks". Bad blocks that are developed during the lifespan of the flash are named "Later Bad Blocks". We implement an efficient bad block management algorithm to detect the factory-produced bad blocks and manages any bad blocks that appear with use. This practice further prevents data being stored into bad blocks and improves the data reliability.

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TRIM

TRIM is a feature which helps improve the read/write performance and speed of solid-state drives (SSD). Unlike hard disk drives (HDD), SSDs are not able to overwrite existing data, so the available space gradually becomes smaller with each use. With the TRIM command, the operating system can inform the SSD which blocks of data are no longer in use and can be removed permanently. Thus, the SSD will perform the erase action, which prevents unused data from occupying blocks all the time.

SMART

SMART, an acronym for Self-Monitoring, Analysis and Reporting Technology, is an open standard that allows a hard disk drive to automatically detect its health and report potential failures. When a failure is recorded by SMART, users can choose to replace the drive to prevent unexpected outage or data loss. Moreover, SMART can inform users of impending failures while there is still time to perform proactive actions, such as copy data to another device.

Over-Provision

Over Provisioning refers to the inclusion of extra NAND capacity in a SSD, which is not visible and cannot be used by users. With Over Provisioning, the performance and IOPS (Input/Output Operations per Second) is improved by providing the controller additional space to manage P/E cycles, which enhances the reliability and endurance as well. Moreover, the write amplification of the SSD becomes lower when the controller writes data to the flash.

Firmware Upgrade

Firmware can be considered as a set of instructions on how the device communicates with the host. Firmware will be upgraded when new features are added, compatibility issues are fixed or read/write performance gets improved.

SmartZIP™

Write data to the NAND Flash costs time. To improve the write speed performance, controller launches with compression technique—SmartZIPTM. Whether a file could be compressed or not depending on the file type, for file types have redundancy data pattern, through our embedded encode engine, we could reduce the amount of data that is actually written to the Flash. Comparing to the SSD without the compression, write efficiency is raised and the SSD endurance is also improved since Flash could be benefit from less data written for a longer SSD lifetime.

ADDITIONAL FEATURES

Low Power Management (DIPM/HIPM Mode)

SATA interfaces contain two low power management states for power saving: Partial and Slumber modes. For Partial mode, the device has to resume to full operation within 10 microseconds, whereas the device will spend 10 milliseconds to become fully operational in the Slumber mode. SATA interfaces allow low power modes to be initiated by Host (HIPM, Host Initiated Power Management) or Device (DIPM, Device Initiated Power Management). As for HIPM, Partial or Slumber mode can be invoked directly by the software. For DIPM, the device will send requests to enter Partial or Slumber mode.

DEVSLP Mode (optional)

With the increasing need of aggressive power/battery life, SATA interfaces include a new feature, Device Sleep (DEVSLP) mode, which helps further reduce the power consumption of the device. DEVSLP enables the device to completely power down the device PHY and other sub-systems, making the device reach a new level of lower power operation. The DEVSLP does not specify the exact power level a device can achieve in the DEVSLP mode, but the power usage can be dropped down to 5mW or less.

Power Loss Protection: Flushing Mechanism

Power Loss Protection is a mechanism to prevent data loss during unexpected power failure. DRAM is a volatile memory and frequently used as temporary cache or buffer between the controller and the NAND flash to improve the SSD performance. However, one major concern of the DRAM is that it is not able to keep data during power failure. Accordingly, the controller applies the GuaranteedFlush Technology, which requests the controller to transfer data to the cache. For the used controller, SDR performs as a cache, and its sizes include up to 32MB. Only when the data is fully committed to the NAND flash will the controller send acknowledgement (ACK) to the host. Such implementation can prevent false-positive performance and the risk of power cycling issues.

Additionally, it is critical for a controller to shorten the time the in-flight data stays in the cache. Thus, the controller applies an algorithm to reduce the amount of data resides in the cache to provide a better performance. This SmartCacheFlush technology allows incoming data to only have a "pit stop" in the cache and then move to the NAND flash at once. If the flash is jammed due to particular file sizes (random 4K), the cache will be treated as an "organizer", consolidating incoming data into groups before written into the flash to improve write amplification.

In sum, with this Flush Management, the controller proves to provide the reliability required by consumer, industrial, and enterprise-level application.

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Advanced Device Security Features (Secure Erase, Write Protect)

Secure Erase is a standard ATA command and will write all “0x00” to fully wipe all the data on hard drives and SSDs. When this command is issued, the SSD controller will empty its storage blocks and return to its factory default settings. When a SSD contains too many bad blocks and data are continuously written in, then the SSD might not be used anymore. Thus, Write Protect is a mechanism to prevent data from being written in and protect the accuracy of data that are already stored in the SSD.

PERFORMANCE AND POWER CONSUMPTION

| Capacity | Flash Structure | Performance | | Power Consumption | | | |
|-----------|-----------------|-----------------|--------------|-------------------|------------|-----------|-------------|
| | | CrystalDiskMark | | Read (mW) | Write (mW) | Idle (mW) | DEVSLP (mW) |
| | | Read (MB/s) | Write (MB/s) | | | | |
| 4GB | 4GB x 1, TSOP | 160 | 50 | 700 | 740 | 280 | 4.9 |
| | 4GB x 1, TSOP | 300 | 50 | 870 | 800 | 265 | 4.9 |
| 8GB | 8GB x 1, TSOP | 165 | 100 | 700 | 740 | 280 | 4.9 |
| | 8GB x 1, TSOP | 320 | 105 | 850 | 770 | 265 | 4.9 |
| 16GB | 16GB x 1, TSOP | 320 | 84 | 1,180 | 1,200 | 262 | 4.9 |
| 30/32GB | 16GB x 2, TSOP | 550 | 160 | 1,185 | 1,300 | 265 | 4.9 |
| 60/64GB | 16GB x 4, TSOP | 550 | 310 | 1,220 | 1,310 | 265 | 4.9 |
| 120/128GB | 64GB x 2, BGA | 550 | 465 | 1,270 | 1,600 | 280 | 4.9 |
| | 32GB x 4, BGA | 550 | 465 | 1,280 | 1,700 | 285 | 4.9 |
| | 32GB x 4, TSOP | 550 | 465 | 1,200 | 1,600 | 265 | 4.9 |
| 240/256GB | 64GB x 4, BGA | 550 | 490 | 1,320 | 2,600 | 285 | 4.9 |
| | 64GB x 4, TSOP | 550 | 465 | 1,250 | 1,555 | 260 | 4.9 |
| 480/512GB | 128GB x 4, BGA | 550 | 490 | 1,450 | 2,690 | 285 | 4.9 |
| | 128GB x 4, TSOP | 550 | 465 | 1,445 | 2,485 | 265 | 4.9 |

NOTES:

1. The performance was measured using CrystalDiskMark with SATA 6Gbps host.
2. Samples were built using Kioxia 15 nm MLC NAND flash.
3. Performance may differ according to flash configuration and platform.
4. The table above is for reference only. The criteria for MP (mass production) and for accepting goods shall be discussed based on different flash configuration.

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TBW

| Capacity | Flash Structure | TBW |
|-----------|-----------------|-----|
| 4GB | 4GB x 1 | 1 |
| 8GB | 8GB x 1 | 3 |
| 16GB | 16GB x 1 | 6 |
| 30/32GB | 16GB x 2 | 13 |
| 60/64GB | 16GB x4 | 30 |
| 120/128GB | 64GB x 2 | 87 |
| | 32GB x 4 | |
| 240/256GB | 64GB x 4 | 198 |
| 480/512GB | 128GB x 4 | 540 |

NOTES:

1. Samples were built using Kioxia 15 nm MLC NAND flash.
2. The test followed JEDEC219A client endurance workload.
3. TBW may differ according to flash configuration and platform.
4. The endurance of SSD could be estimated based on user behaviour, NAND endurance cycles, and write amplification factor. It is not guaranteed by flash vendor.

SUPPLY VOLTAGE

| PARAMETER | RATING |
|-------------------|-------------|
| Operating voltage | 3.3V +/- 5% |

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PRODUCT ORDERING INFORMATION

| PN | Type | Capacity | Technology | Temp range | Grade |
|----------------------|-------|----------|------------|------------|---------|
| RUSMSM004S3SB-P11KI5 | mSATA | 4GB | MLC | 0~70°C | silver |
| RUSMSM008S3SB-P11KI5 | mSATA | 8GB | MLC | 0~70°C | silver |
| RUSMSM016S3SB-P11KI5 | mSATA | 16GB | MLC | 0~70°C | silver |
| RUSMSM030S3SB-P11KI5 | mSATA | 30GB | MLC | 0~70°C | silver |
| RUSMSM032S3SB-P11KI5 | mSATA | 32GB | MLC | 0~70°C | silver |
| RUSMSM060S3SB-P11KI5 | mSATA | 60GB | MLC | 0~70°C | silver |
| RUSMSM064S3SB-P11KI5 | mSATA | 64GB | MLC | 0~70°C | silver |
| RUSMSM120S3SB-P11KI5 | mSATA | 120GB | MLC | 0~70°C | silver |
| RUSMSM128S3SB-P11KI5 | mSATA | 128GB | MLC | 0~70°C | silver |
| RUSMSM240S3SB-P11KI5 | mSATA | 240GB | MLC | 0~70°C | silver |
| RUSMSM256S3SB-P11KI5 | mSATA | 256GB | MLC | 0~70°C | silver |
| RUSMSM480S3SB-P11KI5 | mSATA | 480GB | MLC | 0~70°C | silver |
| RUSMSM512S3SB-P11KI5 | mSATA | 512GB | MLC | 0~70°C | silver |
| RUSMSM004S3GB-P11KI5 | mSATA | 4GB | MLC | -25~85°C | gold |
| RUSMSM008S3GB-P11KI5 | mSATA | 8GB | MLC | -25~85°C | gold |
| RUSMSM016S3GB-P11KI5 | mSATA | 16GB | MLC | -25~85°C | gold |
| RUSMSM030S3GB-P11KI5 | mSATA | 30GB | MLC | -25~85°C | gold |
| RUSMSM032S3GB-P11KI5 | mSATA | 32GB | MLC | -25~85°C | gold |
| RUSMSM060S3GB-P11KI5 | mSATA | 60GB | MLC | -25~85°C | gold |
| RUSMSM064S3GB-P11KI5 | mSATA | 64GB | MLC | -25~85°C | gold |
| RUSMSM120S3GB-P11KI5 | mSATA | 120GB | MLC | -25~85°C | gold |
| RUSMSM128S3GB-P11KI5 | mSATA | 128GB | MLC | -25~85°C | gold |
| RUSMSM240S3GB-P11KI5 | mSATA | 240GB | MLC | -25~85°C | gold |
| RUSMSM256S3GB-P11KI5 | mSATA | 256GB | MLC | -25~85°C | gold |
| RUSMSM480S3GB-P11KI5 | mSATA | 480GB | MLC | -25~85°C | gold |
| RUSMSM512S3GB-P11KI5 | mSATA | 512GB | MLC | -25~85°C | gold |
| RUSMSM004S3DB-P11KI5 | mSATA | 4GB | MLC | -40~85°C | diamond |
| RUSMSM008S3DB-P11KI5 | mSATA | 8GB | MLC | -40~85°C | diamond |
| RUSMSM016S3DB-P11KI5 | mSATA | 16GB | MLC | -40~85°C | diamond |
| RUSMSM030S3DB-P11KI5 | mSATA | 30GB | MLC | -40~85°C | diamond |
| RUSMSM032S3DB-P11KI5 | mSATA | 32GB | MLC | -40~85°C | diamond |
| RUSMSM060S3DB-P11KI5 | mSATA | 60GB | MLC | -40~85°C | diamond |
| RUSMSM064S3DB-P11KI5 | mSATA | 64GB | MLC | -40~85°C | diamond |
| RUSMSM120S3DB-P11KI5 | mSATA | 120GB | MLC | -40~85°C | diamond |
| RUSMSM128S3DB-P11KI5 | mSATA | 128GB | MLC | -40~85°C | diamond |
| RUSMSM240S3DB-P11KI5 | mSATA | 240GB | MLC | -40~85°C | diamond |
| RUSMSM256S3DB-P11KI5 | mSATA | 256GB | MLC | -40~85°C | diamond |
| RUSMSM480S3DB-P11KI5 | mSATA | 480GB | MLC | -40~85°C | diamond |
| RUSMSM512S3DB-P11KI5 | mSATA | 512GB | MLC | -40~85°C | diamond |

PIN ASSIGNMENT AND DESCRIPTIONS

| Pin # | mSATA Pin | Description | Pin # | mSATA Pin | Description |
|-------|-----------|--|-------|-----------|---|
| 1 | NC | No Connect | 27 | SATA GND | SATA Ground Return Pin |
| 2 | +3.3V | 3.3V Source | 28 | NC | No Connect |
| 3 | NC | No Connect | 29 | SATA GND | SATA Ground Return Pin |
| 4 | DGND | Digital GND | 30 | NC | No Connect |
| 5 | NC | No Connect | 31 | RXN (in) | Host Transmitter Differential Signal Pair |
| 6 | NC | No Connect | 32 | NC | No Connect |
| 7 | NC | No Connect | 33 | RXP (in) | Host Transmitter Differential Signal Pair |
| 8 | NC | No Connect | 34 | DGND | Digital GND |
| 9 | DGND | Digital GND | 35 | SATA GND | SATA Ground Return Pin |
| 10 | NC | No Connect | 36 | NC | No Connect |
| 11 | NC | No Connect | 37 | SATA GND | SATA Ground Return Pin |
| 12 | NC | No Connect | 38 | NC | No Connect |
| 13 | NC | No Connect | 39 | +3.3V | 3.3V Source |
| 14 | NC | No Connect | 40 | DGND | Digital GND |
| 15 | DGND | Digital GND | 41 | +3.3V | 3.3V Source |
| 16 | NC | No Connect | 42 | NC | No Connect |
| 17 | NC | No Connect | 43 | NC | No Connect |
| 18 | DGND | Digital GND | 44 | DEVSLP | Enter/Exit DevSleep |
| 19 | NC | No Connect | 45 | NC | Reserved pin |
| 20 | NC | No Connect | 46 | NC | No Connect |
| 21 | SATA GND | SATA Ground Return Pin | 47 | NC | Reserved pin |
| 22 | NC | No Connect | 48 | NC | No Connect |
| 23 | TXP (out) | Host Receiver Differential Signal Pair | 49 | DAS | Device Activity Signal |
| 24 | +3.3V | 3.3V Source | 50 | DGND | Digital GND |
| 25 | TXN (out) | Host Receiver Differential Signal Pair | 51 | GND | Default connect to GND |
| 26 | SATA GND | SATA Ground Return Pin | 52 | +3.3V | 3.3V Source |

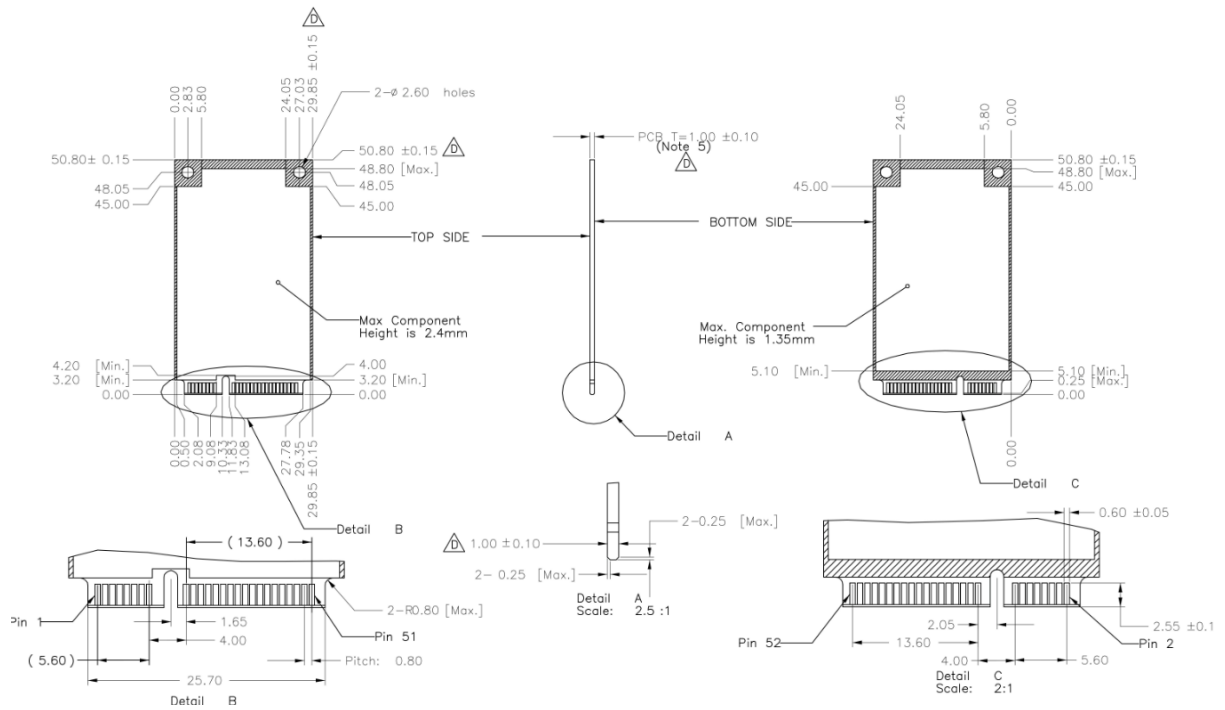
SUPPORTED ATA COMMAND LIST

| Op-Code | Command Description | Op-Code | Command Description | |
|---------|-----------------------------------|---------|-------------------------|---|
| 00h | NOP | C9h | Read DMA without Retry | |
| 06h | Data Set Management | CAh | Write DMA | |
| 10h-1Fh | Recalibrate | CBh | Write DMA without Retry | |
| 20h | Read Sectors | CEh | Write Multiple FUA EXT | |
| 21h | Read Sectors without Retry | E0h | Standby Immediate | |
| 24h | Read Sectors EXT | E1h | Idle Immediate | |
| 25h | Read DMA EXT | E2h | Standby | |
| 27h | Read Native Max Address EXT | E3h | Idle | |
| 29h | Read Multiple EXT | E4h | Read Buffer | |
| 2Fh | Read Log EXT | E5h | Check Power Mode | |
| 30h | Write Sectors | E6h | Sleep | |
| 31h | Write Sectors without Retry | E7h | Flush Cache | |
| 34h | Write Sectors EXT | E8h | Write Buffer | |
| 35h | Write DMA EXT | E9h | READ BUFFER DMA | |
| 37h | Set Native Max Address EXT | EAh | Flush Cache EXT | |
| 38h | CFA Write Sectors Without Erase | EBh | Write Buffer DMA | |
| 39h | Write Multiple EXT | ECh | Identify Device | |
| 3Dh | Write DMA FUA EXT | EFh | Set Features | |
| 3Fh | Write Long EXT | EFh | 02h | Enable volatile write cache |
| 40h | Read Verify Sectors | EFh | 03h | Set transfer mode |
| 41h | Read Verify Sectors without Retry | EFh | 05h | Enable the APM feature set |
| 42h | Read Verify Sectors EXT | EFh | 10h | Enable use of SATA features et |
| 44h | Zero EXT | EFh | 10h 02h | Enable DMA Setup FIS Auto-Activate optimization |
| 45h | Write Uncorrectable EXT | EFh | 10h 03h | Enable Device-initiated interface power state (DIPM) transitions |
| 47h | Read Log DMA EXT | EFh | 10h 06h | Enable Software Settings Preservation (SSP) |
| 57h | Write Log DMA EXT | EFh | 10h 07h | Enable Device Automatic Partial to Slumber transitions |
| 60h | Read FPDMA Queued | EFh | 10h 09h | Enable Device Sleep |
| 61h | Write FPDMA Queued | EFh | 55h | Disable read look-ahead |
| 70h-7Fh | Seek | EFh | 66h | Disable reverting to power-on defaults |
| 90h | Execute Device Diagnostic | EFh | 82h | Disable volatile write cache |
| 91h | Initialize Device Parameters | EFh | 85h | Disable the APM feature set |
| 92h | Download Microcode | EFh | 90h | Disable use of SATA feature set |
| 93h | Download Microcode DMA | EFh | 90h 02h | Disable DMA Setup FIS Auto-Activate optimization |
| B0h | SMART | EFh | 90h 03h | Disable Device-initiated interface power state (DIPM) transitions |
| B0h | D0h | EFh | 90h 06h | Disable Software Settings Preservation (SSP) |
| B0h | D1h | EFh | 90h 07h | Disable Device Automatic Partial to Slumber transitions |
| B0h | D2h | EFh | 90h 09h | Disable Device Sleep |

| | | | | | |
|-----|----------------------|---|-----|-----|---------------------------------------|
| B0h | D3h | SMART SAVE ATTRIBUTE VALUES | EFh | AAh | Enable read look-ahead |
| B0h | D4h | SMART EXECUTE OFF-LINE IMMEDIATE | EFh | CCh | Enable reverting to power-on defaults |
| B0h | D5h | SMART READ LOG | F1h | | Security Set Password |
| B0h | D6h | SMART WRITE LOG | F2h | | Security Unlock |
| B0h | D8h | SMART ENABLE OPERATIONS | F3h | | Security Erase Prepare |
| B0h | D9h | SMART DISABLE OPERATIONS | F4h | | Security Erase Unit |
| B0h | DAh | SMART RETURN STATUS | F5h | | Security Freeze Lock |
| B0h | DBh | SMART ENABLE/DISABLE AUTOMATIC OFF-LINE | F6h | | Security Disable Password |
| B1h | Device Configuration | | F8h | | Read Native Max Address |
| B4h | Sanitize | | F9h | | Set Max Address |
| C4h | Read Multiple | | F9h | 01h | SET MAX SET PASSWORD |
| C5h | Write Multiple | | F9h | 02h | SET MAXLOCK |
| C6h | Set Multiple Mode | | F9h | 03h | SET MAX UNLOCK |
| C8h | Read DMA | | F9h | 04h | SET MAX FREEZE LOCİK |

PHYSICAL DIMENSION

Dimension: 50.8mm (L) x 29.85mm (W) x 4.00mm (H)



STANDARDS & REFERENCES

The following table is to list out the standards that have been adopted for designing the product.

| STANDARD USED | ACRONYM/SOURCE |
|-------------------------|--|
| RoHS | Restriction of Hazardous Substances Directive; please contact us for further information |
| Serial ATA Revision 3.2 | http://www.sata-io.org |
| ATA-8 spec | http://www.t13.org |
| CE | Consumer electronics certification; please contact us for further information. |

SAFETY PRECAUTIONS

Do not bend, crush, drop, or place heavy objects on top of the Product. Do not use tweezers, pliers or similar items that could damage the Product. Take particular care when inserting or removing the Product. Stop using the Product when the Product does not work properly. Failure to follow these instructions could result in fire, damage to the Product and/or other property, and/or personal injury including burns and electric shock.

Keep out of reach of small children. Accidental swallowing may cause suffocation or injury. Contact a doctor immediately if you suspect a child has swallowed the Product.

Do not directly touch the interface pins, put them in contact with metal, strike them with hard objects or cause them to short. Do not expose to static electricity.

Do not disassemble or modify the Product. This may cause electric shock, damage to the Product or fire.

NOTES ON USAGE

The Product contains nonvolatile semiconductor memory. Do not use the Product in accordance with a method of usage other than that written in the manual. This may cause the destruction or loss of data.

To protect against accidental data loss, you should back up your data frequently on more than one type of storage media. Wilk Elektronik S.A. assumes no liability for destruction or loss of data recorded on the Card for any reason.

When used over a long period of time or repeatedly, the reading, writing and deleting capabilities of the Product will eventually fail, and the performance speed of the Product may decrease below the original speed specific to the Product's applicable class.

If the Product is to be transferred or destroyed, note that the data it contained may still be recoverable unless it is permanently deleted by third-party deletion software or similar means beforehand.

Product is intended for use in general electronics applications and selected industrial applications and any other specific applications as expressly stated in this document. Product is neither intended nor warranted for use in equipment or systems where failure may cause loss of human life, bodily injury, serious property damage or serious public impact ("Unintended Use"). Unintended Use includes, without limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, medical equipment or equipment used to control combustions or explosions. Do not use Product for Unintended Use unless specifically permitted in this document.

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